

Introduction to Nanotechnology and Nanoscience – Class#15

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Outline

□Review

□ Nanowire Applications – thermoelectric effect
□ Small Project Assignments

□Paper 6

□Nanowire Integration and Assembly



Capping Control

Nanowire Synthesis -Strategies



Anisotropic Crystal

Adapted after Y. Xia et al., Adv. Mat. 15, 353 (2003)

lid Catalyst Growth Methode

- Different shape of the gold at the tip of the nanowire.
 - A liquid gold droplet has a smooth, almost half spherical shape
 - solid gold shows planes, edges, and corners that may easily be identified
- Gold nanodroplets remained liquid
 - authors observed this VLS-type growth mostly for nanowires with relatively large diameters.
- Gold droplet became solid as the temperature fell below TE
 - In contrast, for nanowires with relatively small diameters
 - Nanowires continued to grow, but much more slowly than in the case of VLS growth





NW FET

Vasileios

- Paper used Si NWs
- Chemically modified to change conductivity based on pH
- Same principle can be applied for conductivity based on biochemicals





N

HW#4 Problem 2

d. Number of carbon atoms per unit cell N.

number of hexagons per 1D unit cell

$$N = \frac{2(n^2 + m^2 + nm)}{d_R}$$



Total carbon atoms per hexagon is 6 * 1/3 = 2

Nanowire for Battery Electrodes



] Typical Battery (my figure)

Issues: after charge/discharge cycles, film and particle-based electrodes have discontinuity and prevent electron/iron



Good contact with current collector Nanowires for battery electrode? (Nature Nanotechnology, Vol. 3, pp31-35, 2008)



Why Nanowires?

- 2μm

Initial

10 m V

300

- 1. High surface area
- 2. Direct connection to substrate
- 3. Possible stress relieve

Issues

- 1. Which material is best for this?
- 2. How to grow these nanowires?
- 3. Problems?



200 -

Number of nanowires

100-

100

200

Diameter (nm)



Thermoelectric Figure of Merit (*ZT***)**

Coefficient of Performance

$$\text{COP}_{\text{max}} = \frac{T_c}{T_h - T_c} \frac{\sqrt{1 + zT_m} - T_h / T_c}{\sqrt{1 + zT_m} + 1}$$

where





Nanowires



22 nm diameter Si nanowire, P. Yang, Berkeley

- Increased phonon-boundary scattering
- Modified phonon dispersion
 - \rightarrow Suppressed thermal conductivity
- Ref: Chen and Shakouri, J. Heat Transfer 124, 242





Rough Silicon Nanowire for Thermoelectric Cooling?



Thermoelectric effects

Issues: Low figure of merit (ZT) such that low energy transfer efficiency



□ Rough silicon nanowires for thermoelectric cooling? (Nature, Vol. 451, pp163-165, 2008)

Why Nanowires?



- 1. High surface area
- 2. Low thermal conductivity for High $ZT = S^2 \sigma T/k$

Issues

- 1. Which material is best for this?
- 2. How to grow these nanowires?
- 3. Problems?



Plans & Discussions

□ Small Project – due 3/21/2023 (before the Spring Break) – one-page ppt slide due at bcourse. You will present you project during the lectures of 3/14 & 3/19



Example for 1-page Slides

Silver Nanocrystal functionalized Silicon Nanowire Hot Wire Ammonia Detector

(AgNcSiNWHW NH3 Detector)

- A portable, non-invasive, near-instantaneous measure of kidney function
- NH3 is filtered out of blood by kidneys
 - concentration of NH3 in exhaled by patient can indicate kidney function
- Cui et al. Fast and Selective Room-Temperature Ammonia Sensors (2012)
 - Functionalized CNTs
 - Alignment via E-field
- \square Propose:
 - Functionalized silicon nanowires for increased sensitivity
 - Localized heating growth method for ease of fabrication
 - Packaged as a hand-held device





Process for Synthesizing Protein-Mimicking, End-Linked SWCNT Chains and Measuring their Enthalpy of Folding

Joshua Price ME 118 Proposal March 23, 2017





Grappling Gecko Gloves

Jason Becker

- Geckos' feet are covered in small hair like structures call setae
- Gecko fingertips have a total surface area of 227 mm³ and have been measured to withstand a maximum force of 20.1 N [1]
- Corresponds to an adhesive force of $10^{-4} \frac{nN}{nm^2}$
- Artificial nanoscale adhesives with adhesive force of 1.6 \pm 0.5 \times 10⁻² $\frac{nN}{nm^2}$ have been developed [2]
- Amounts to over 2000 times required adhesion to support human weight
- CVD used to grow nanotubes, which are subsequently embedded and stabilized in PMMA matrix



Figure 1. Scanning electron micrographs of a) tokay gecko toes, b) higher magnification of tokay gecko toes, and c) artificially made nanoscale adhesives [1].

^{1.} Autumn, K., How gecko toes stick - The powerful, fantastic adhesive used by geckos is made of nanoscale hairs that engage tiny forces, inspiring envy among human imitators. American Scientist, 2006. 94(2): p. 124-132. 2. Yurdumakan, B., et al., Synthetic gecko foot-hairs from multiwalled carbon nanotubes. Chemical Communications, 2005(30): p. 3799-3801.



Paper 6



Change in R due to:

- Solubility of species into gate changes geometry
- Partial charge transfer from species to gate
- both

A polymer gate FET sensor array for detecting organic vapours, J.A Covington et Al FET-type gas sensors: A review, Seongbin Hong



NW FET

Vasileios

- 1. Easy to control diameter
- 2. Easy to dope
- 3. Easy to functionalize
- 4. Si based NW benefit from semiconductor knowledge base
- Robust manufacturing



Doping of semiconductor nanowires, Jesper Wallentin et al.

Experimental set-up

- Nanosensor formed by modifying the silcon oxide surface of a silicon nanowire (SiNW) solid state FET with 3-aminopropyltri-ethoxysilane (APTES)
- Changes in surface charge undergoing protonization or deprotonization will chemically gate the SiNW
- SiNWs are prepared by a nanocluster-mediated vapor-liquid-solid growth method
- Devices are fashioned by flow aligning SiNWs on oxidized silicon substrates
- Ohmic electrical contacts to the NW ends by using electron-beam lithography
- The Conductance (dl/dV) versus gate voltage is nearly linear

The response of the conductance to changes in solution pH

- Evaluated by the use of a cell comprised of a microfluidic channel established between a poly(dimethylsiloxane) (PDMS) mold and the SiNW/substrate

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- Nanowire conductance is linear over the pH range from 2 to 9



Interpretation

- Termination of -NH₂ and -SiOH groups (due to the linking of APTES to the SiNW oxide surface)
- Low pH:
 - $-NH_2$ protonates to NH_3^+
 - Acts as a positive gate
 - Deplets hole carriers in the p-type SiNW
 - Decreases the conductance
- High pH:
 - -SiOH deprotonates to SiO⁻
 - Increases the conductance
- Linear response due to an approximately linear change in the total surface charge density



Also supported by measurements on unmodifed SiNWs

- Here the conductance shows a nonlinear pH dependence.
- In agreement with previous measurements of the pH-dependent surface charge density derived from silica



Functionalization of SiNWs with biotin

- Functionalized SiNWs with biotin-streptavidin and studied the well-characterized ligand-receptor binding of biotin-streptavidin
- Condunctance increases rapdily upon addition of a 250 nM streptavidin solution to a constant value (binding of the negatively charged streptavidin species to the p-type SiNW surface)
- Conductance maintained after the addition of pure buffer solution (small dissociation rate for biotin-streptavidin)

Control Experiments

• If changes in conductance for biotin-modified SiNWs were only because of interactions between biotin and streptavidin



Control Tests

B) BiotinSiNW > 250 nM Streptavidin > Pure Buffer

C) Just SiNW > 250 nM Streptavidin > Pure Buffer

D) Biotin SiNW > Streptavidin that's already

binded to biotion > Pure Buffer

E) BiotinSiNW > 25 pM Streptavidin > Pure Buffer



Problems

- If biotin-modified nanowire is binded before the experiment, then there will be no change in conductance
- Reversible binding of monoclonal antibiotin (m-antibiotin) with biotin



m-Antibiotin Test

A) BiotinSiNW > 3 μ M m-antibiotin > Pure Buffer

B) Just SiNW > 3 µM m-antibiotin > Pure Buffer

C) Biotin SiNW > bovine IgG > 3 µM m-antibiotin

D) BiotinSiNW > Different m-antibiotin concentrations



Ca²⁺ Test

A) Calmodulin-Terminated SiNW > 25 μM Ca²⁺ > Pure
Buffer

B) Just SiNW > 25 μ M Ca²⁺ > Pure Buffer

Conclusion: Nanowire sensors can also calcium ions





Nanowire Nanolasers Reports

Room-Temperature Ultraviolet Nanowire Nanolasers

Michael H. Huang,¹ Samuel Mao,² Henning Feick,³ Haoquan Yan,¹ Yiying Wu,¹ Hannes Kind,¹ Eicke Weber,³ Richard Russo,² Peidong Yang^{1,3}*

www.sciencemag.org SCIENCE VOL 292 8 JUNE 2001



"Vertically Aligned"















Nanostructure Synthesis

- CVD (Chemical Vapor Deposition) with VLS (Vapor-Liquid-Solid) growth
- Silane (SiH₄) vapor phase reactant
- Gold-Palladium (AuPd) solid phase, metal catalyst
- Silicon from the thermal decomposition of silane and AuPd form a *liquid* alloy at the eutectic temperature of AuPd-Si (high temperature)



Vapor-Liquid-Solid Growth

- σ_{LV} is the liquid-vapor interface free energy, V_L is the molar volume of the liquid, σ is the vapor phase of supersaturation, R is the gas constant and T is the temperature
- Competing conditions: energy gain of condensation and the energy cost in the interfacial energy
- Equilibrium conditions results in nanowires of order 100 nm or larger





CNTs Synthesis Methods

Arc Discharge Method

- Uniform Diameters
- Fewest Defects
- SW or MWNTs
- Highest quality
- Gaseous, Laser-Vaporization, Pyrolysis, other CVD
- Require high temperature chamber







Nanoscale Assembly



- Synthesis in <u>high temperature</u> tubes
- Fluidic self-assembly
- Focus-Ion-Beam or E-beam for serial bonding

Our Approach

- <u>Post-CMOS</u>, <u>site-specific</u> synthesis, assembly and bonding using <u>MEMS</u> as the "bridge"
- Nano + MEMS + Microelectronics with on-chip process control and sensing microelectronics



Room Temperature Chamber

- CMOS-compatible nanostructures
- Site-specific CVD activated by resistive heating





Room Temperature Chamber

- CMOS-compatible nanostructures
- Site-specific CVD activated by resistive heating





One-Mask Process



Silicon Nanowires – 1st Demo

